Carry Lookhead Generator

HITACHI

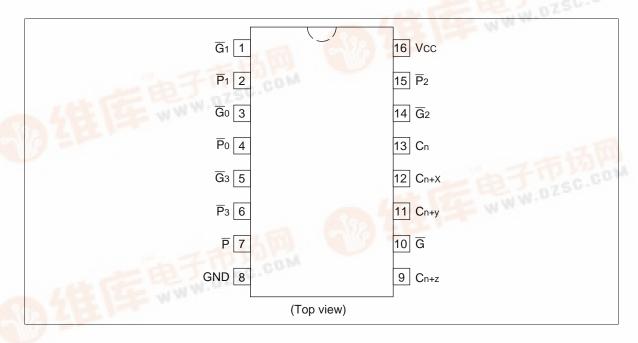
Description

The HD74AC182/HD74ACT182 is a high-speed carry lookahead generator. It is generally used with the HD74AC181 or HD74AC381 4-bit arithmetic logic unit to provide high-speed lookahead over word lengths of more than four bits.

Features

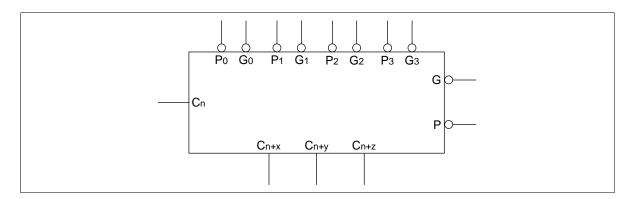
- Outputs Source/Sink 24 mA
- HD74ACT182 has TTL-Compatible Inputs

Pin Arrangement





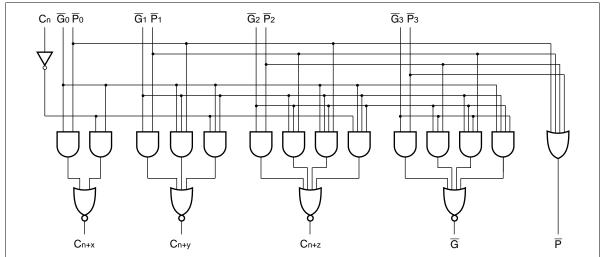
Logic Symbol



Pin Names

Cn	Carry Input
$\overline{\mathrm{G}}_{0},\overline{\mathrm{G}}_{2}$	Carry Generate Inputs (Active Low)
$\overline{\mathbf{G}}_{1}$	Carry Generate Input (Active Low)
$\overline{\mathbf{G}}_3$	Carry Generate Input (Active Low)
$\overline{P}_0, \overline{P}_1$	Carry Propagate Inputs (Active Low)
$\overline{\mathbf{P}}_2$	Carry Propagate Input (Active Low)
$\overline{\mathbf{P}}_3$	Carry Propagate Input (Active Low)
C_{n+x} to C_{n+z}	Carry Outputs
\overline{G}	Carry Generate Output (Active Low)
\overline{P}	Carry Propagate Output (Active Low)

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Functional Description

The HD74AC182/HD74ACT182 carry lookahead generator accepts up to four pairs of Active Low Carry Propagate (\overline{P}_0 to \overline{P}_3) and Carry Generate (\overline{G}_0 to \overline{G}_3) signals and an Active High Carry input (Cn) and provides anticipated Active High carries (C_{n+x} , C_{n+y} , C_{n+z}) across four groups of binary adders. The HD74AC182/HD74ACT182 also has Active Low Carry Propagate (\overline{P}) and Carry Generate (\overline{G}) outputs which may be used for further level of lookahead. The logic equations provided at the outputs are:

$$\begin{split} &C_{n+x} = G_0 + P_0 C_n \\ &C_{n+y} = G_1 + P_1 G_0 + P_1 P_0 C_n \\ &C_{n+z} = G_2 + P_2 G_1 + P_2 P_1 G_0 + P_2 P_1 P_0 C_n \\ &G = \overline{G_3 + P_3 G_2} + P_3 P_2 G_1 + P_3 P_2 P_1 G_0 \\ &P = \overline{P_3 P_2 P_1 P_0} \end{split}$$

Also, the HD74AC182/HD74ACT182 can be used with binary ALUs in an active Low or active High input operand mode. The connections (Figure a) to and from the ALU to the carry lookahead generator are identical in both cases. Carries are rippled between lookahead blocks. The critical speed path follows the circled numbers. There are several possible arrangements for the carry interconnects, but all achieve about the same speed. A 28-bit ALU is formed by dropping the last HD74AC182/HD74ACT182.

Truth Table

Inpu	Inputs					Outputs							
C _n	$\overline{G}_{\scriptscriptstyle{0}}$	$\overline{P}_{\scriptscriptstyle{0}}$	G ₁	\overline{P}_{1}	$\overline{G}_{\scriptscriptstyle 2}$	$\overline{P}_{\scriptscriptstyle 2}$	$\overline{G}_{\scriptscriptstyle{3}}$	$\overline{P}_{\scriptscriptstyle 3}$	C _{n + x}	C _{n + y}	C _{n+z}	G	P
Χ	Н	Н							L				
L	Н	Х							L				
Χ	L	Х							Н				
Н	Χ	L							Н				
Χ	Χ	Х	Н	Н						L			
Χ	Н	Н	Н	Х						L			
L	Н	Χ	Н	Χ						L			
Χ	Х	Χ	L	Χ						Н			
Χ	L	Х	Х	L						Н			
Н	Х	L	Χ	L						Н			
Χ	Х	Х	Χ	Χ	Н	Н					L		
Χ	Χ	Х	Н	Н	Н	Х					L		
Χ	Н	Н	Н	Χ	Н	Χ					L		
L	Н	Х	Н	Χ	Н	Χ					L		
Χ	Χ	Х	Χ	Χ	L	Х					Н		
Χ	Х	Х	L	Х	Χ	L					Н		
Χ	L	Х	Χ	L	Χ	L					Н		
Н	Χ	L	Χ	L	Χ	L					Н		
	Χ		Χ	Χ	Χ	Χ	Н	Н				Н	
	Х		Χ	Х	Н	Н	Н	Χ				Н	
	Χ		Н	Н	Н	Χ	Н	Χ				Н	
	Н		Н	Х	Н	Х	Н	Χ				Н	
	Χ		Х	Х	Х	Х	L	Х				L	
	Х		Х	Х	L	Х	Х	L				L	
-	Χ		L	Х	Х	L	Х	L				L	
	L		Х	L	Х	L	Х	L				L	
		Н		Х		Х		Х					Н
-		Х		Н		Х		Х					Н
		Х		Х		Н		Х					Н
		Х		Х		Х		Н					Н
		L		L		L		L					L

H: High Voltage Level
L: Low Voltage Level

X : Immaterial

DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I _{cc}	80	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, Ta = Worst case
Maximum quiescent supply current	I _{cc}	8.0	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, Ta = 25°C
Maximum I _{cc} /input (HD74ACT182)	I _{CCT}	1.5	mA	$V_{IN} = V_{CC} - 2.1 \text{ V}, V_{CC} = 5.5 \text{ V},$ Ta = Worst case

AC Characteristics: HD74AC182

			Ta = +25°C C _L = 50 pF		Ta = -40° C to $+85^{\circ}$ C C _L = 50 pF			
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Propagation delay	t _{PLH}	3.3	1.0	8.0	10.5	1.0	11.5	ns
P_n to P		5.0	1.0	5.5	8.0	1.0	9.0	
Propagation delay	t _{PHL}	3.3	1.0	8.0	10.5	1.0	11.5	ns
P_n to P		5.0	1.0	5.5	8.0	1.0	9.0	
Propagation delay	t _{PLH}	3.3	1.0	9.5	12.0	1.0	13.0	ns
C_n to $C_{n+x, y, z}$		5.0	1.0	7.5	10.0	1.0	11.0	
Propagation delay	t _{PHL}	3.3	1.0	9.0	12.0	1.0	13.0	ns
C_n to $C_{n+x, y, z}$		5.0	1.0	7.0	10.0	1.0	11.0	
Propagation delay	t _{PLH}	3.3	1.0	10.5	13.0	1.0	14.0	ns
P_n or G_n to $C_{n+x, y, z}$		5.0	1.0	8.0	10.5	1.0	11.5	
Propagation delay	t _{PHL}	3.3	1.0	11.5	14.0	1.0	15.5	ns
P_n or G_n to $C_{n+x, y, z}$		5.0	1.0	9.0	11.5	1.0	12.5	_

Note: 1. Voltage Range 3.3 is 3.3 V \pm 0.3 V Voltage Range 5.0 is 5.0 V \pm 0.5 V

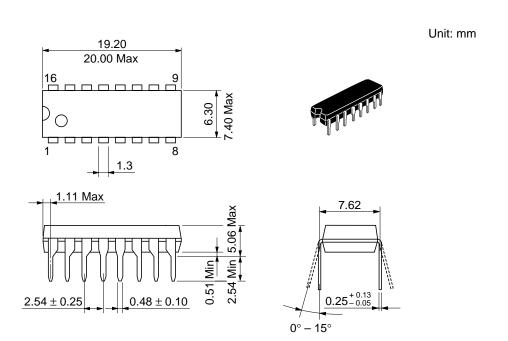
AC Characteristics: HD74ACT182

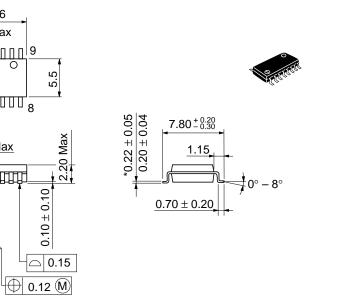
		V _{cc} (V)*1	Ta = +25°C C _∟ = 50 pF			Ta = -40°C to +85°C C _L = 50 pF		
Item	Symbol		Min	Тур	Max	Min	Max	Unit
Propagation delay P _n to P	t _{PLH}	5.0	1.0	7.0	9.0	1.0	10.0	ns
Propagation delay P _n to P	t _{PHL}	5.0	1.0	8.0	10.0	1.0	11.0	ns
Propagation delay C_n to $C_{n+x, y, z}$	t _{PLH}	5.0	1.0	9.0	11.0	1.0	12.0	ns
Propagation delay C_n to $C_{n+x, y, z}$	t _{PHL}	5.0	1.0	9.0	11.0	1.0	12.0	ns
Propagation delay P_n or G_n to $C_{n+x, y, z}$	t _{PLH}	5.0	1.0	9.0	11.0	1.0	12.0	ns
Propagation delay P_n or G_n to $C_{n+x, y, z}$	t _{PHL}	5.0	1.0	10.0	12.5	1.0	13.5	ns

Note: 1. Voltage Range 5.0 is 5.0 V \pm 0.5 V

Capacitance

Item	Symbol	Тур	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{cc} = 5.5 V
Power dissipation capacitance	C_{PD}	50.0	pF	$V_{CC} = 5.0 \text{ V}$





10.06 10.5 Max 16 7 7 9

1 00000008

0.80 Max

1.27

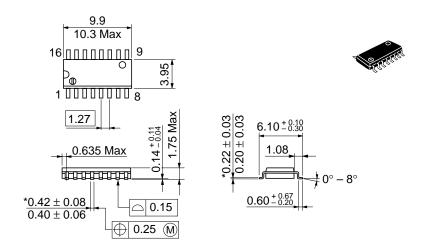
 $^{*}0.42 \pm 0.08$ 0.40 ± 0.06

5.5

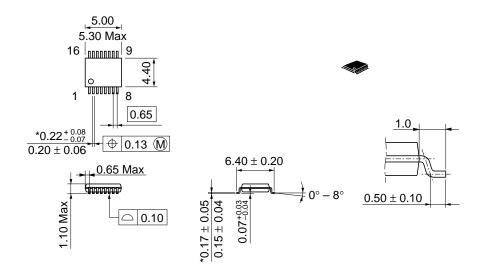
 $\boldsymbol{0.10\pm0.10}$

Unit: mm









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